

NSI45025AZT1G

Constant Current Regulator & LED Driver

45 V, 25 mA ± 10%, 1.4 W Package

The linear constant current regulator (CCR) is a simple, economical and robust device designed to provide a cost-effective solution for regulating current in LEDs. The CCR is based on patent-pending Self-Biased Transistor (SBT) technology and regulates current over a wide voltage range. It is designed with a negative temperature coefficient to protect LEDs from thermal runaway at extreme voltages and currents.

The CCR turns on immediately and is at 25% of regulation with only 0.5 V V_{AK} . It requires no external components allowing it to be designed as a high or low-side regulator. The high anode-cathode voltage rating withstands surges common in Automotive, Industrial and Commercial Signage applications. The CCR comes in thermally robust packages and is qualified to AEC-Q101 standard.

Features

- Robust Power Package: 1.4 Watts
- Wide Operating Voltage Range
- Immediate Turn-On
- Voltage Surge Suppressing – Protecting LEDs
- AEC-Q101 Qualified
- SBT (Self-Biased Transistor) Technology
- Negative Temperature Coefficient
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Automobile: Chevron Side Mirror Markers, Cluster, Display & Instrument Backlighting, CHMSL, Map Light
- AC Lighting Panels, Display Signage, Decorative Lighting, Channel Lettering
- Switch Contact Wetting
- Application Note AND8391/D – Power Dissipation Considerations
- Application Note AND8349/D – Automotive CHMSL

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|--|---------------------|---------------------|------------------|
| Anode-Cathode Voltage | $V_{AK\text{ Max}}$ | 45 | V |
| Reverse Voltage | V_R | 500 | mV |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |
| ESD Rating: Human Body Model Machine Model | ESD | Class 1C Class B | |

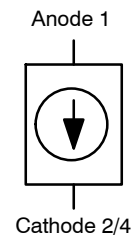
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

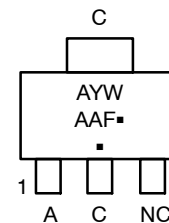
<http://onsemi.com>

$I_{reg(SS)} = 25\text{ mA}$
@ $V_{AK} = 7.5\text{ V}$



SOT-223
CASE 318E
STYLE 2

MARKING DIAGRAM



A = Assembly Location
Y = Year
W = Work Week
AAF = Specific Device Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping† |
|---------------|-------------------|------------------|
| NSI45025AZT1G | SOT-223 (Pb-Free) | 1000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSI45025AZT1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|----------------|------|-----|-------|------|
| Steady State Current @ $V_{AK} = 7.5\text{ V}$ (Note 1) | $I_{reg(SS)}$ | 22.5 | 25 | 27.5 | mA |
| Voltage Overhead (Note 2) | $V_{overhead}$ | | 1.8 | | V |
| Pulse Current @ $V_{AK} = 7.5\text{ V}$ (Note 3) | $I_{reg(P)}$ | 23.4 | 26 | 28.65 | mA |
| Capacitance @ $V_{AK} = 7.5\text{ V}$ (Note 4) | C | | 2.6 | | pF |
| Capacitance @ $V_{AK} = 0\text{ V}$ (Note 4) | C | | 6.9 | | pF |

- $I_{reg(SS)}$ steady state is the voltage (V_{AK}) applied for a time duration ≥ 10 sec, using FR-4 @ 300 mm² 2 oz. Copper traces, in still air.
- $V_{overhead} = V_{in} - V_{LEDs}$. $V_{overhead}$ is typical value for 75% $I_{reg(SS)}$.
- $I_{reg(P)}$ non-repetitive pulse test. Pulse width $t \leq 300\ \mu\text{sec}$.
- $f = 1\text{ MHz}$, 0.02 V RMS .

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|--------------|----------------------------|
| Total Device Dissipation (Note 5) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 954 7.6 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 5) | $R_{\theta JA}$ | 131 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 5) | $R_{\psi JL4}$ | 40.8 | $^\circ\text{C/W}$ |
| Total Device Dissipation (Note 6) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1074 8.6 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 6) | $R_{\theta JA}$ | 116 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 6) | $R_{\psi JL4}$ | 39.9 | $^\circ\text{C/W}$ |
| Total Device Dissipation (Note 7) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1150 9.2 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 7) | $R_{\theta JA}$ | 109 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 7) | $R_{\psi JL4}$ | 42 | $^\circ\text{C/W}$ |
| Total Device Dissipation (Note 8) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1300 10.4 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 8) | $R_{\theta JA}$ | 96 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 8) | $R_{\psi JL4}$ | 39.4 | $^\circ\text{C/W}$ |
| Total Device Dissipation (Note 9) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1214 9.7 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 9) | $R_{\theta JA}$ | 103 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 9) | $R_{\psi JL4}$ | 40.2 | $^\circ\text{C/W}$ |
| Total Device Dissipation (Note 10) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1389 11.1 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient (Note 10) | $R_{\theta JA}$ | 90 | $^\circ\text{C/W}$ |
| Thermal Reference, Junction-to-Lead 4 (Note 10) | $R_{\psi JL4}$ | 37.7 | $^\circ\text{C/W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

- FR-4 @ 100 mm², 1 oz. copper traces, still air.
- FR-4 @ 100 mm², 2 oz. copper traces, still air.
- FR-4 @ 300 mm², 1 oz. copper traces, still air.
- FR-4 @ 300 mm², 2 oz. copper traces, still air.
- FR-4 @ 500 mm², 1 oz. copper traces, still air.
- FR-4 @ 500 mm², 2 oz. copper traces, still air.

NOTE: Lead measurements are made by non-contact methods such as IR with treated surface to increase emissivity to 0.9.

Lead temperature measurement by attaching a T/C may yield values as high as 30% higher $^\circ\text{C/W}$ values based upon empirical measurements and method of attachment.

TYPICAL PERFORMANCE CURVES

Minimum FR-4 @ 300 mm², 2 oz Copper Trace, Still Air

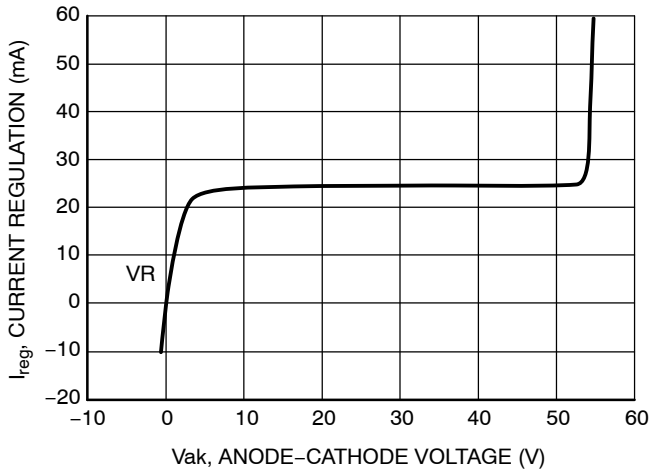


Figure 1. General Performance Curve for CCR

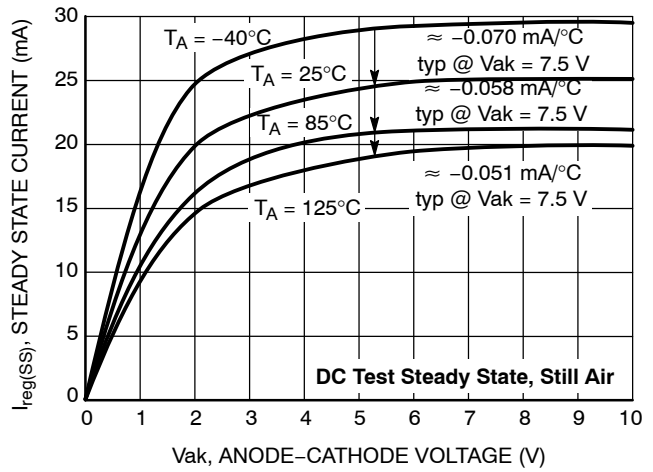


Figure 2. Steady State Current ($I_{reg(SS)}$) vs. Anode-Cathode Voltage (V_{ak})

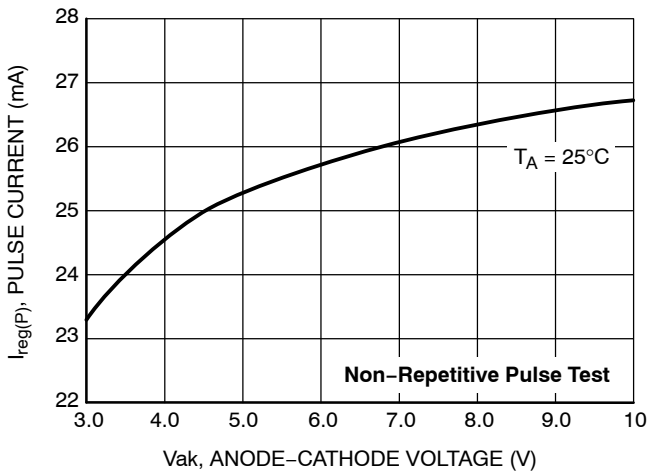


Figure 3. Pulse Current ($I_{reg(P)}$) vs. Anode-Cathode Voltage (V_{ak})

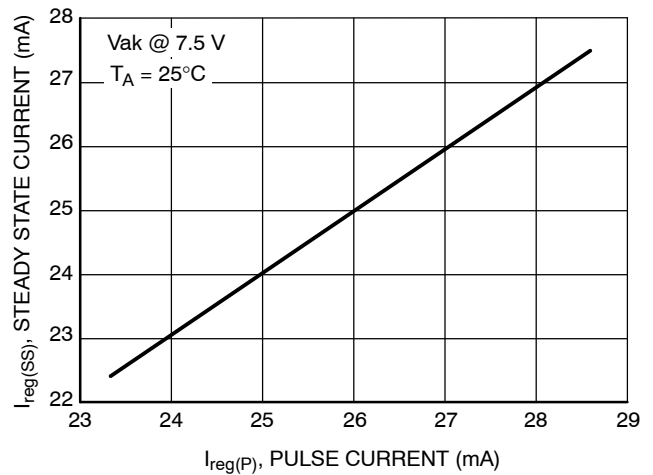


Figure 4. Steady State Current vs. Pulse Current Testing

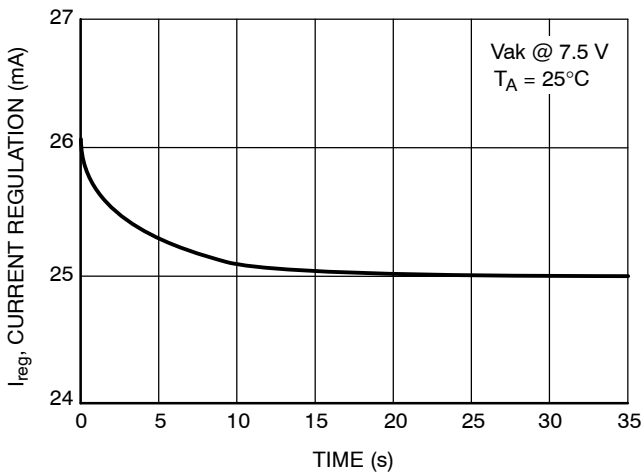


Figure 5. Current Regulation vs. Time

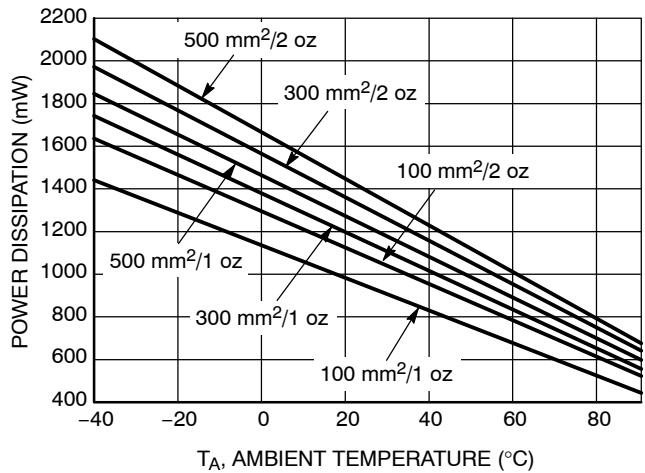
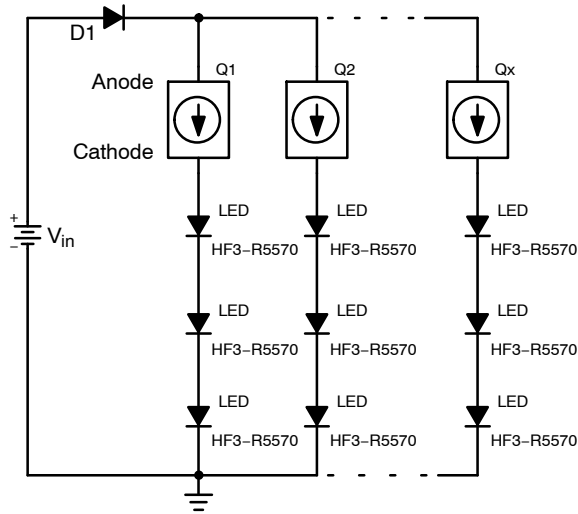


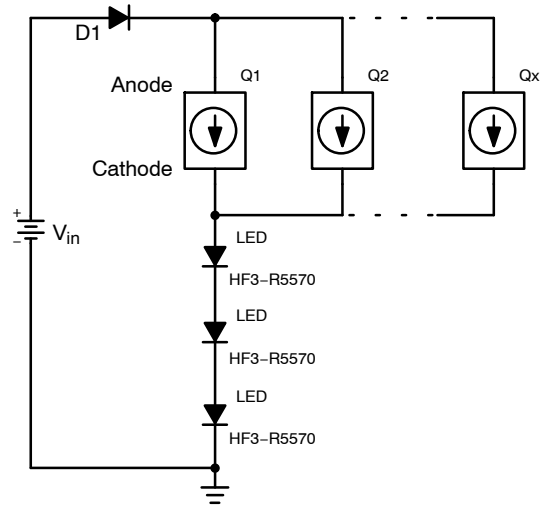
Figure 6. Power Dissipation vs. Ambient Temperature @ $T_J = 150^\circ\text{C}$

APPLICATIONS



**Figure 7. Typical Application Circuit
(25 mA each LED String)**

Number of LED's that can be connected is determined by:
D1 is a reverse battery protection diode
 $LED's = (V_{in} - Q_X V_F + D1 V_F) / LED V_F$
Example: $V_{in} = 12 \text{ Vdc}$, $Q_X V_F = 3.5 \text{ Vdc}$, $D1 V_F = 0.7 \text{ V}$
 $LED V_F = 2.2 \text{ Vdc @ 25 mA}$
 $(12 \text{ Vdc} - 4.2 \text{ Vdc}) / 2.2 \text{ Vdc} = 3 \text{ LEDs in series.}$



**Figure 8. Typical Application Circuit
(75 mA each LED String)**

Number of LED's that can be connected is determined by:
D1 is a reverse battery protection diode
Example: $V_{in} = 12 \text{ Vdc}$, $Q_X V_F = 3.5 \text{ Vdc}$, $D1 V_F = 0.7 \text{ V}$
 $LED V_F = 2.6 \text{ Vdc @ 75 mA}$
 $(12 \text{ Vdc} - (3.5 + 0.7 \text{ Vdc})) / 2.6 \text{ Vdc} = 3 \text{ LEDs in series.}$
Number of Drivers = LED current / 25 mA
 $75 \text{ mA} / 25 \text{ mA} = 3 \text{ Drivers (Q1, Q2, Q3)}$

Comparison of LED Circuit using CCR vs. Resistor Biasing

| ON Semiconductor CCR Design | Resistor Biased Design |
|---|---|
| Constant brightness over full Automotive Supply Voltage (more efficient), see Figure 9 | Large variations in brightness over full Automotive Supply Voltage |
| Little variation of power in LEDs, see Figure 10 | Large variations of current (power) in LEDs |
| Constant current extends LED strings lifetime, see Figure 9 | High Supply Voltage/ Higher Current in LED strings limits lifetime |
| Current decreases as voltage increases, see Figure 9 | Current increases as voltage increases |
| Current supplied to LED string decreases as temperature increases (self-limiting), see Figure 2 | LED current decreases as temperature increases |
| No resistors needed | Requires costly inventory (need for several resistor values to match LED intensity) |
| Fewer components, less board space required | More components, more board space required |
| Surface mount component | Through-hole components |

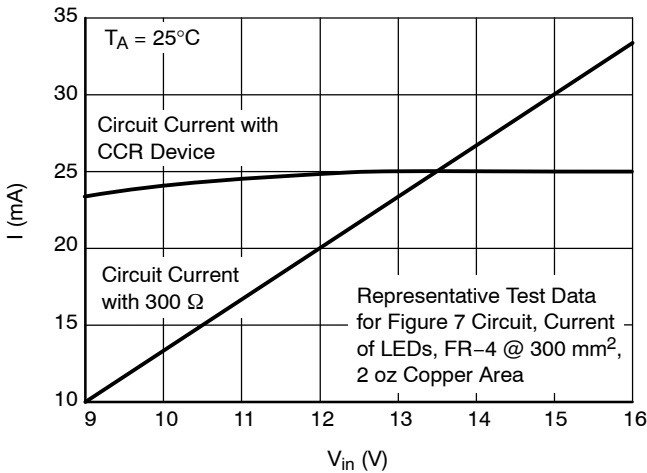


Figure 9. Series Circuit Current

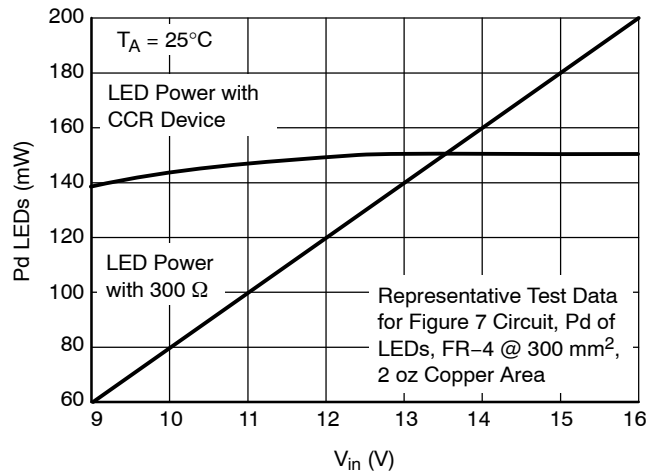


Figure 10. LED Power

Current Regulation: Pulse Mode ($I_{reg(P)}$) vs DC Steady-State ($I_{reg(SS)}$)

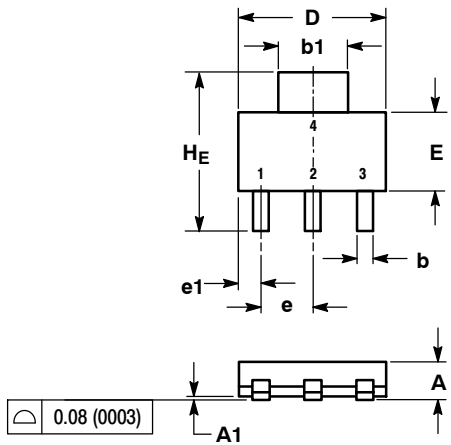
There are two methods to measure current regulation: Pulse mode ($I_{reg(P)}$) testing is applicable for factory and incoming inspection of a CCR where test times are a minimum. ($t \leq 300 \mu\text{s}$). DC Steady-State ($I_{reg(SS)}$) testing is applicable for application verification where the CCR will be operational for seconds, minutes, or even hours. ON Semiconductor has correlated the difference in $I_{reg(P)}$ to

$I_{reg(SS)}$ for stated board material, size, copper area and copper thickness. $I_{reg(P)}$ will always be greater than $I_{reg(SS)}$ due to the die temperature rising during $I_{reg(SS)}$. This heating effect can be minimized during circuit design with the correct selection of board material, metal trace size and weight, for the operating current, voltage, board operating temperature (T_A) and package. (Refer to Thermal Characteristics table).

NSI45025AZT1G

PACKAGE DIMENSIONS

SOT-223 (TO-261)
CASE 318E-04
ISSUE M



NOTES:

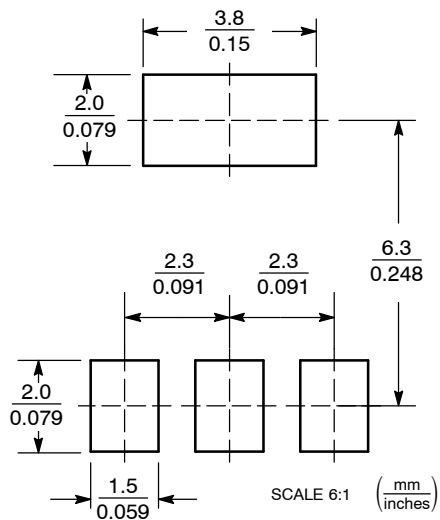
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 1.50 | 1.63 | 1.75 | 0.060 | 0.064 | 0.068 |
| A1 | 0.02 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.60 | 0.75 | 0.89 | 0.024 | 0.030 | 0.035 |
| b1 | 2.90 | 3.06 | 3.20 | 0.115 | 0.121 | 0.126 |
| c | 0.24 | 0.29 | 0.35 | 0.009 | 0.012 | 0.014 |
| D | 6.30 | 6.50 | 6.70 | 0.249 | 0.256 | 0.263 |
| E | 3.30 | 3.50 | 3.70 | 0.130 | 0.138 | 0.145 |
| e | 2.20 | 2.30 | 2.40 | 0.087 | 0.091 | 0.094 |
| e1 | 0.85 | 0.94 | 1.05 | 0.033 | 0.037 | 0.041 |
| L1 | 1.50 | 1.75 | 2.00 | 0.060 | 0.069 | 0.078 |
| HE | 6.70 | 7.00 | 7.30 | 0.264 | 0.276 | 0.287 |
| θ | 0° | - | 10° | 0° | - | 10° |

STYLE 2:

1. ANODE
2. CATHODE
3. NC
4. CATHODE

SOLDERING FOOTPRINT



ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru